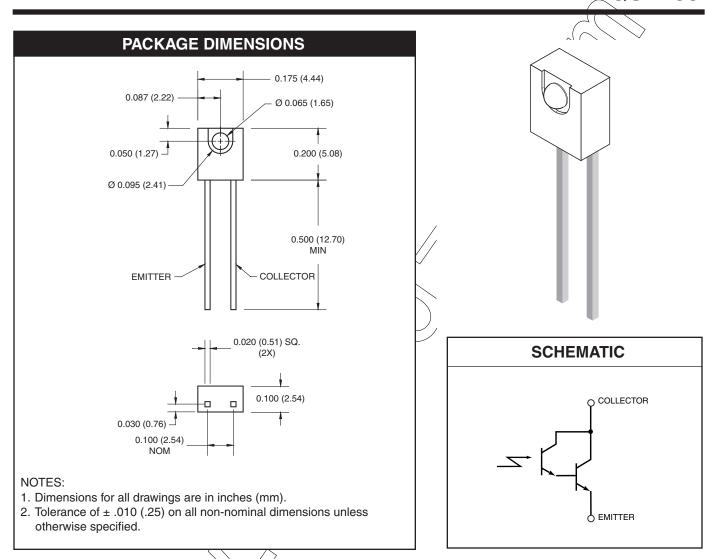


QSE133



DESCRIPTION

The QSE133 is a silicon photodarlington encapsulated in a wide angle, infrared transparent, black plastic sidelooker package.

FEATURES

- NPN silicon phototransistor
- · Package type: Sidetooker
- Medium wide reception angle, 50°
- Package material and color: black epoxy
- Matched emitter: QEE113
- Daylight filter
- High sensitivity



QSE133

ABSOLUTE MAXIMUM RATINGS (T _A = 25°C unless otherwise specified)							
Parameter	Symbol	Rating	Unit				
Operating Temperature	T _{OPR}	-40 to +100	°C				
Storage Temperature	T _{STG}	-40 to +100	°C				
Soldering Temperature (Iron) ^(2,3,4)	T _{SOL-I}	240 for 5 sec	°C				
Soldering Temperature (Flow) ^(2,3)	T _{SOL-F}	260 for 10 sec	°C				
Collector Emitter Voltage	V _{CE}	30	V				
Emitter Collector Voltage	V _{EC}	5	V				
Power Dissipation ⁽¹⁾	PD	100	mW				

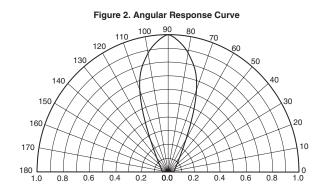
NOTES:

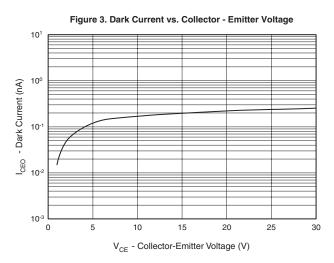
- 1. Derate power dissipation linearly 1.33 mW/°C above 25°C.
- 2. RMA flux is recommended.
- 3. Methanol or isopropyl alcohols are recommended as cleaning agents.
- 4. Soldering iron 1/16" (1.6 mm) minimum from housing.
- 5. $\lambda = 880 \text{ nm (AlGaAs)}.$

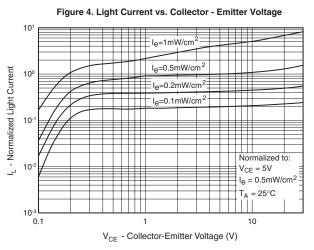
ELECTRICAL / OPTICAL CHARACTERISTICS (T _A =25°C unless otherwise specified)								
Parameter	Test Conditions	Symbol	Min	Тур	Max	Units		
Peak Sensitivity		λ _{PS}	_	880	_	nM		
Reception Angle		Θ		±25	_	Deg.		
Collector Emitter Dark Current	$V_{CE} = 10 \text{ V}, E_e \neq 0$	I _{CEO}	_	_	100	nA		
Collector-Emitter Breakdown	I _C = 1 mA	BV _{CEO}	30	_	_	V		
Emitter-Collector Breakdown	I _E = 100 μA	BV _{ECO}	5	_	_	V		
On-State Collector Current ⁽⁵⁾	$E_e = 0.25 \text{ mW/cm}^2, V_{CE} = 5 \text{ V}$	I _{C(ON)}	9.0	_	_	mA		
Saturation Voltage ⁽⁵⁾	$E_{\rm a} = 0.5 \text{ mW/cm}^2$, $I_{\rm C} = 0.4 \text{ mA}$	V _{CE(SAT)}	_	_	1.0	V		
Rise Time	$V_{CC} = 0.15$ mA, $V_{CC} = 5$ V,	t _r	_	20	_	μs		
Fall Time	$R_{L} = 100\Omega$	t _f	_	50	_	μs		

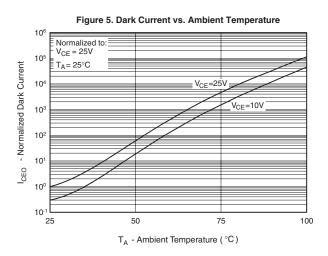


QSE133











QSE133

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